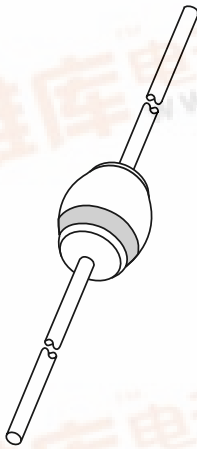


**DISCRETE SEMICONDUCTORS**

# DATA SHEET



## **BYV99** Ultra fast low-loss controlled avalanche rectifier

Product specification  
Supersedes data of May 1993

1996 Feb 19

## Ultra fast low-loss controlled avalanche rectifier

# BYV99

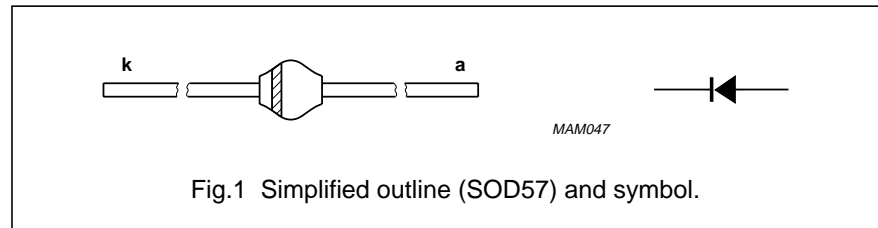
### FEATURES

- Glass passivated
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.

### DESCRIPTION

Rugged glass SOD57 package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		–	600	V
$V_R$	continuous reverse voltage		–	600	V
$I_{F(AV)}$	average forward current	$T_{tp} = 50\text{ °C}$ ; lead length = 10 mm see Fig. 2; averaged over any 20 ms period; see also Fig. 6	–	1.00	A
		$T_{amb} = 60\text{ °C}$ ; PCB mounting (see Fig.10); see Fig. 3; averaged over any 20 ms period; see also Fig. 6	–	0.55	A
$I_{FRM}$	repetitive peak forward current	$T_{tp} = 50\text{ °C}$ ; see Fig. 4	–	9	A
		$T_{amb} = 60\text{ °C}$ ; see Fig. 5	–	5	A
$I_{FSM}$	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{jmax}$ prior to surge; $V_R = V_{RRMmax}$	–	20	A
$E_{RSM}$	non-repetitive peak reverse avalanche energy	$L = 120\text{ mH}$ ; $T_j = T_{jmax}$ prior to surge; inductive load switched off	–	10	mJ
$T_{stg}$	storage temperature		–65	+175	°C
$T_j$	junction temperature		–65	+150	°C

# Ultra fast low-loss controlled avalanche rectifier

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## ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	forward voltage	$I_F = 1\text{ A}$ ; $T_j = T_{j\text{max}}$ ; see Fig. 7	–	–	1.5	V
		$I_F = 1\text{ A}$ ; see Fig. 7	–	–	2.7	V
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1\text{ mA}$	700	–	–	V
$I_R$	reverse current	$V_R = V_{RRM\text{max}}$ ; see Fig. 8	–	–	5	$\mu\text{A}$
		$V_R = V_{RRM\text{max}}$ ; $T_j = 150\text{ °C}$ ; see Fig. 8	–	–	75	$\mu\text{A}$
$t_{rr}$	reverse recovery time	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$ ; measured at $I_R = 0.25\text{ A}$ ; see Fig. 12	–	–	15	ns
$C_d$	diode capacitance	$f = 1\text{ MHz}$ ; $V_R = 0\text{ V}$ ; see Fig. 9	–	75	–	pF
$\left  \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F = 1\text{ A}$ to $V_R \geq 30\text{ V}$ and $dI_F/dt = -1\text{ A}/\mu\text{s}$ ; see Fig.11	–	–	3	$\text{A}/\mu\text{s}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-tp}}$	thermal resistance from junction to tie-point	lead length = 10 mm	46	K/W
$R_{th\ j\text{-a}}$	thermal resistance from junction to ambient	note 1	100	K/W

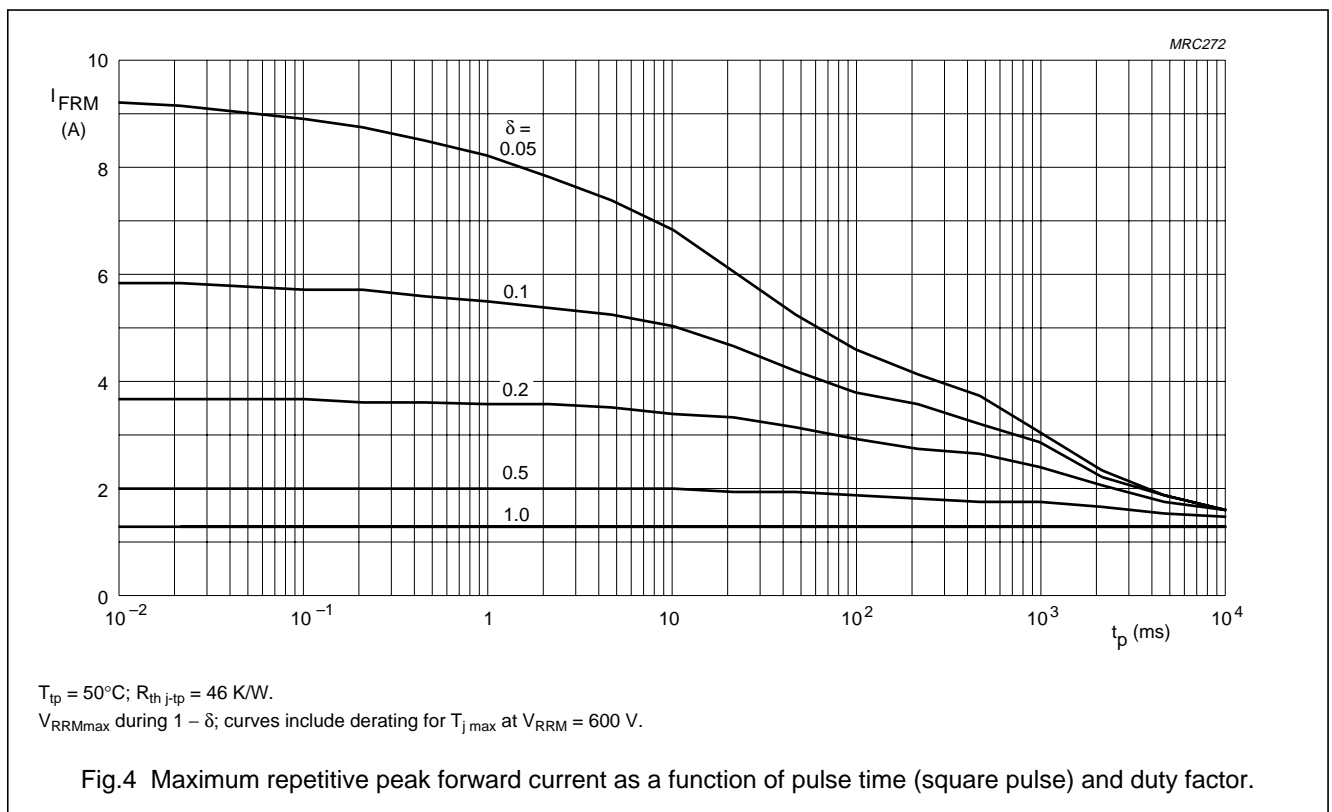
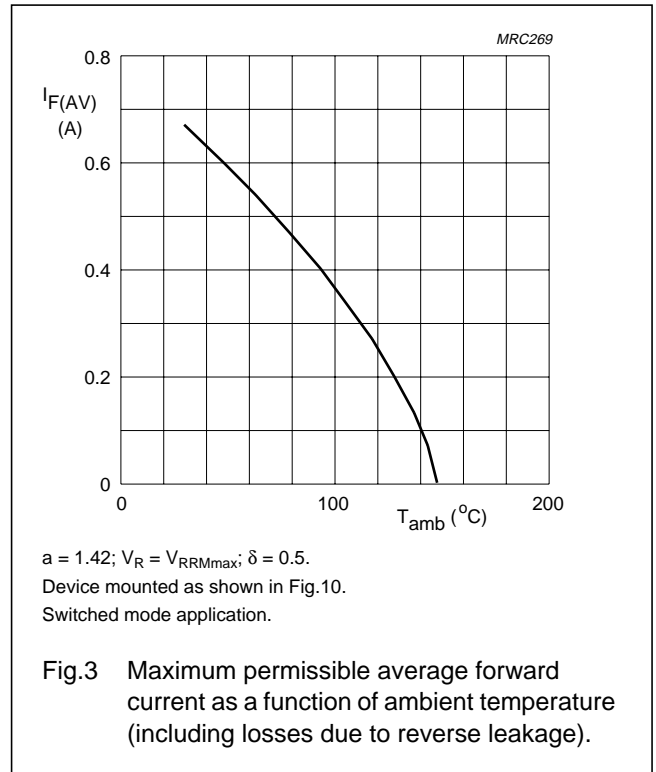
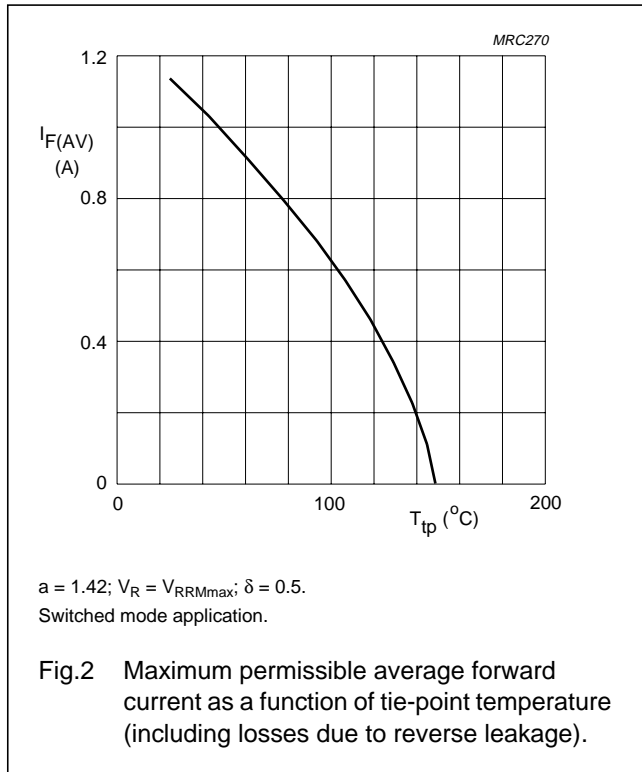
### Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer  $\geq 40\ \mu\text{m}$ , see Fig.10. For more information please refer to the "General Part of associated Handbook".

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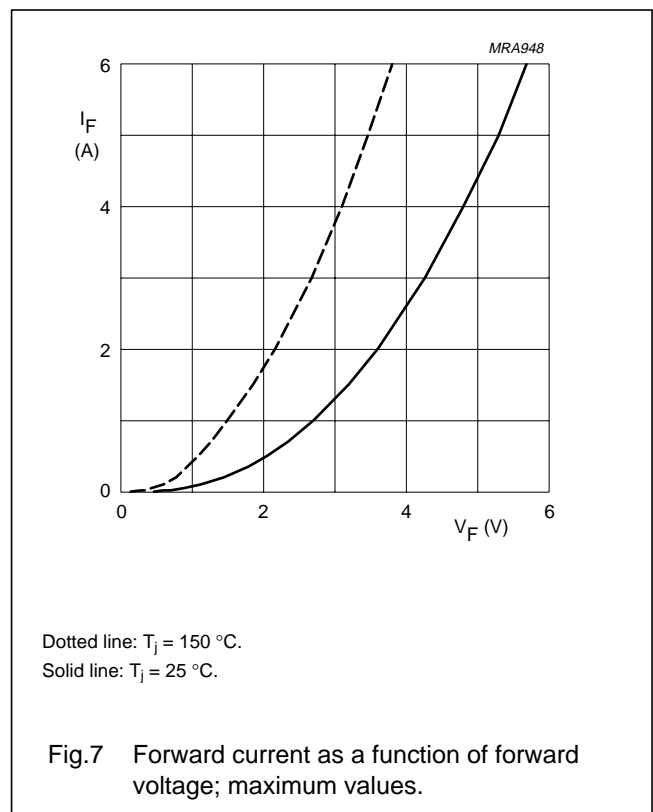
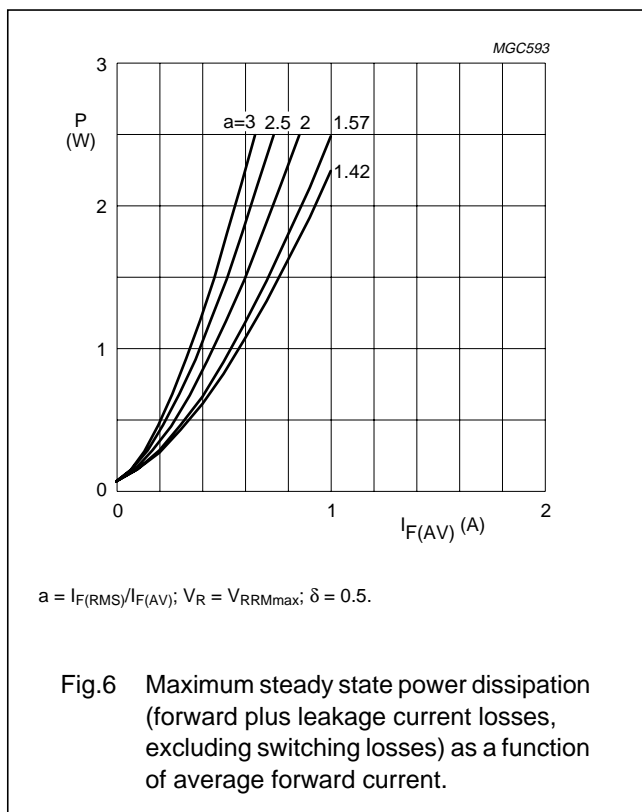
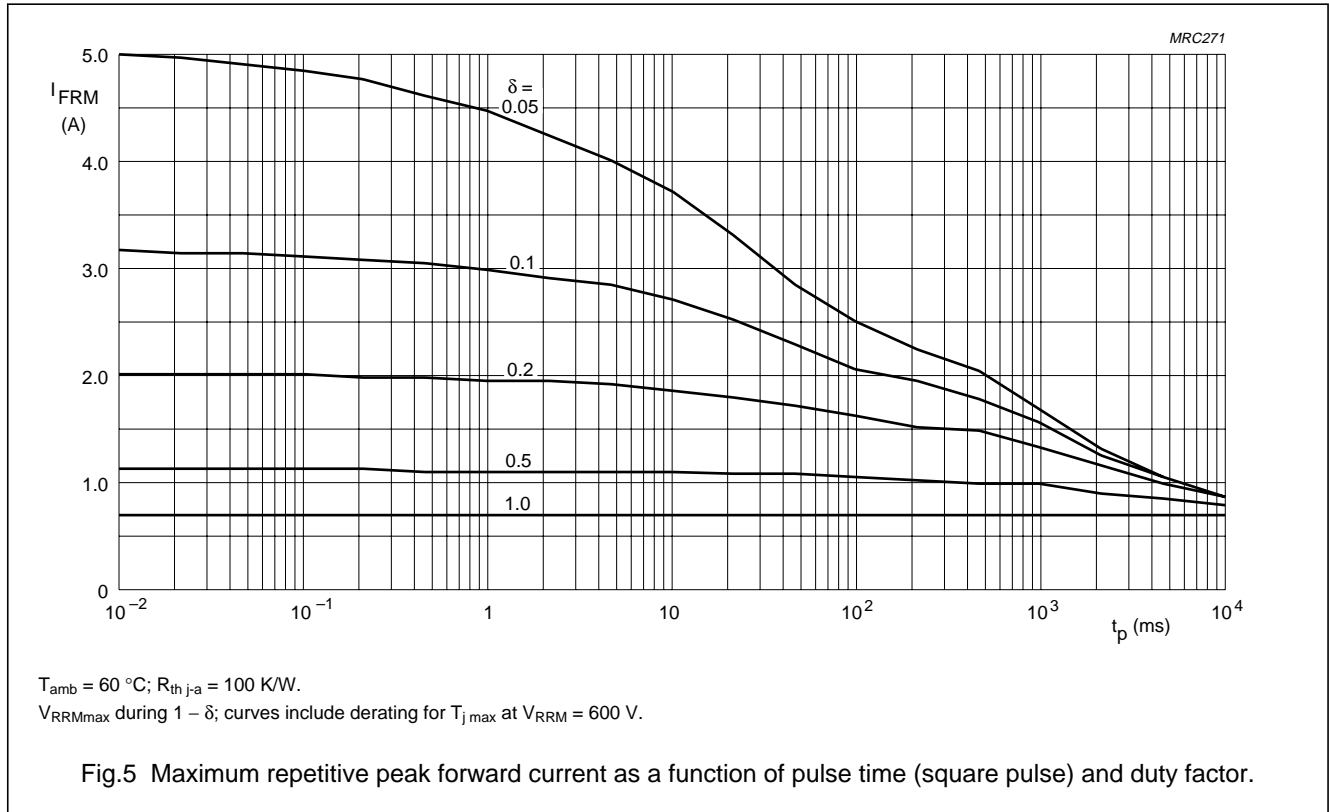
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GRAPHICAL DATA



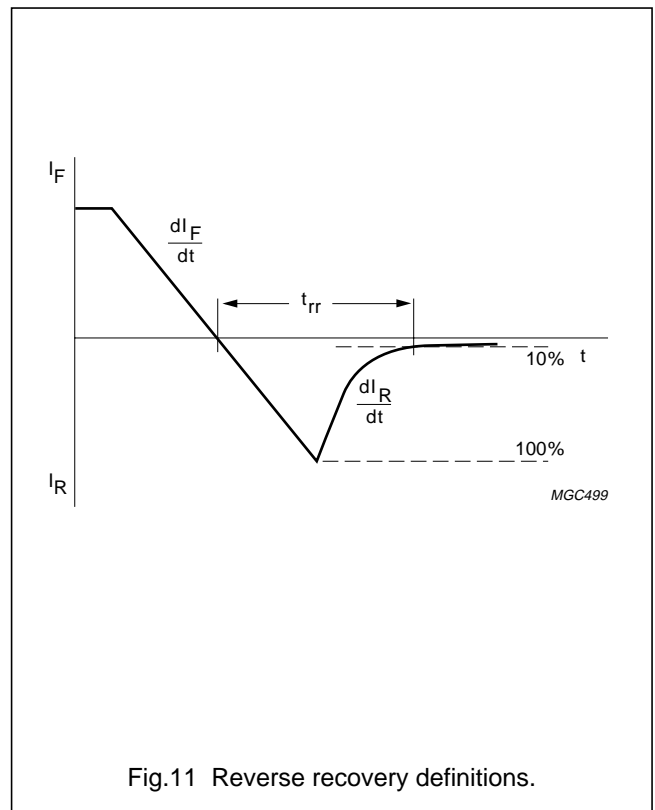
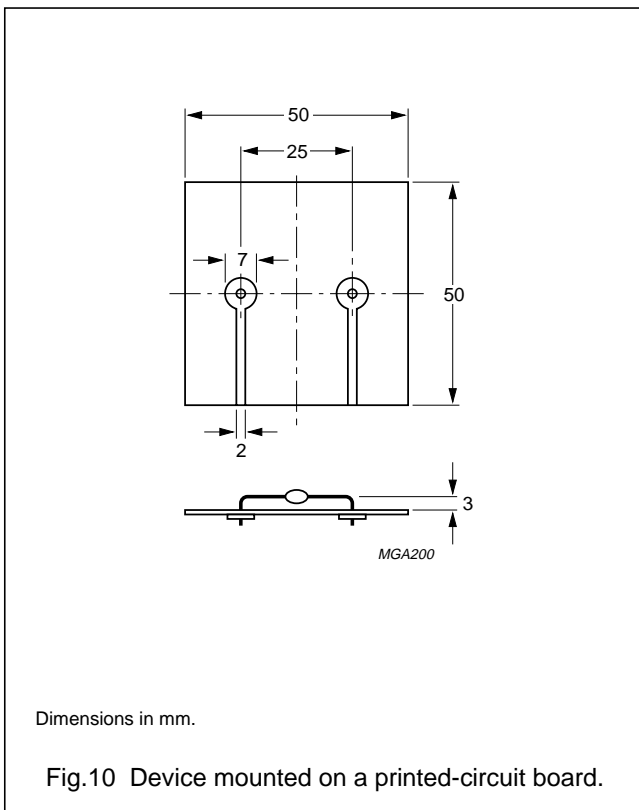
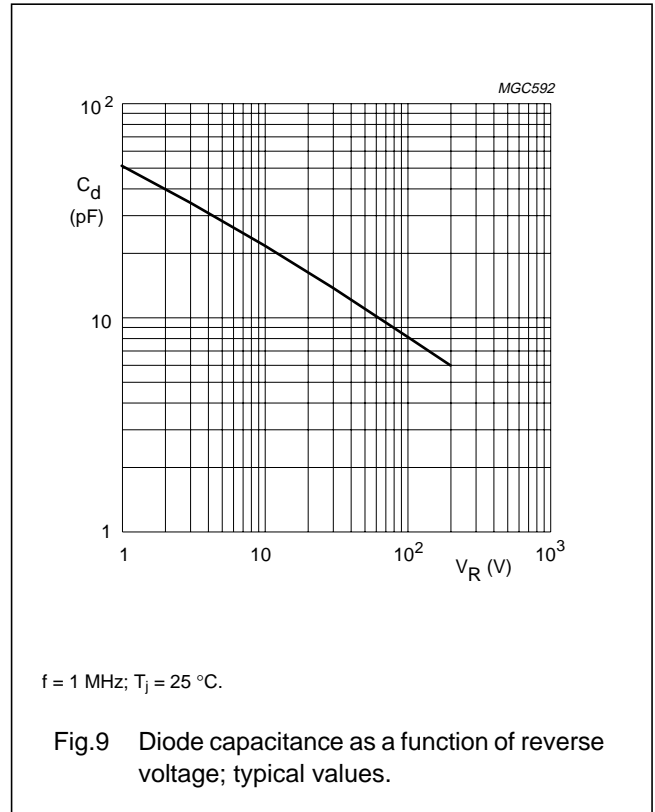
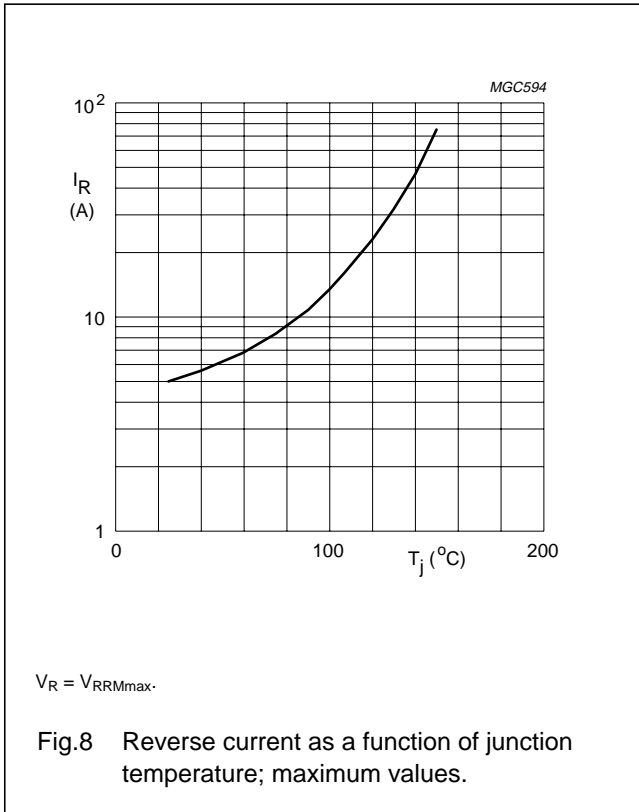
Ultra fast low-loss controlled avalanche rectifier

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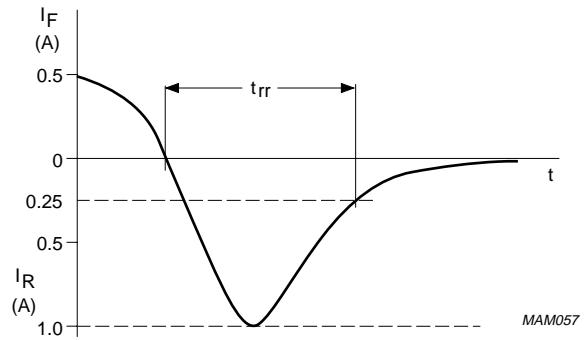
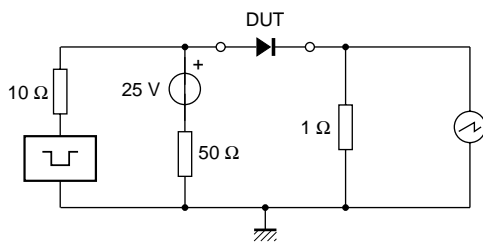
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# Ultra fast low-loss controlled avalanche rectifier

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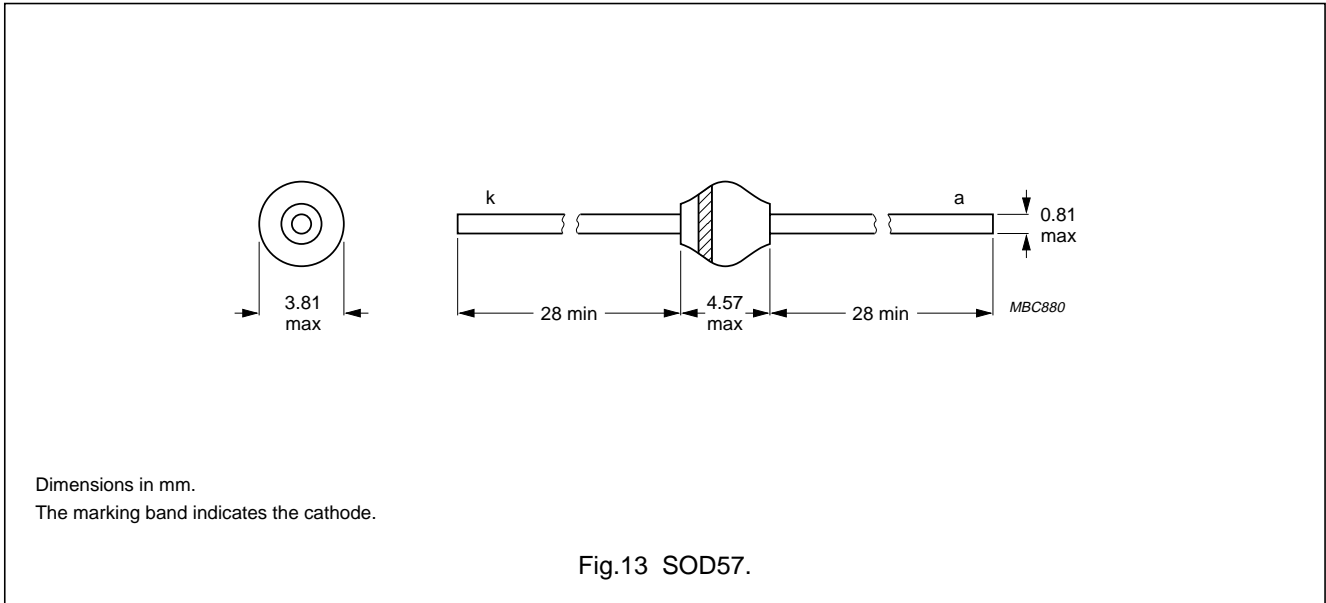
Input impedance oscilloscope: 1 MΩ, 22 pF;  $t_r \leq 7$  ns.  
Source impedance: 50 Ω;  $t_r \leq 15$  ns.

Fig.12 Test circuit and reverse recovery time waveform and definition.

Ultra fast low-loss  
controlled avalanche rectifier

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PACKAGE OUTLINE



DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.